Simple LCD CCFL-backlight Resonant Inverter

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간단한 LCD CCFL 백라이트 공진형 인버터

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Abstract This paper presents a simple LCD CCFL-backlight resonant inverter. First, in introduction various conventional inverter topologies for the CCFL are reviewed, briefly, and then, in each main subject the proposed inverter is explained, in detail. The proposed inverter utilizes a new class-E resonant circuit with a single-switch and is controlled by a single-chip microcontroller, which is very simple. Moreover, the proposed inverter can ensure resonant zero voltage switching (ZVS) under most operating conditions and performs simply the digital dimming control. It is shown through experimental results that the proposed inverter has good performance for the LCD CCFL-backlight.

Key Words: LCD CCFL-backlight, Resonant inverter, Single-chip microcontroller, ZVS, Digital dimming control.

1. Introduction

The proliferation of liquid crystal display (LCD) monitors and notebook computers places an ever increasing demand on display technology. The LCD with cold cathode fluorescent lamp (CCFL) best satisfies display performance, size, efficiency and cost.

The best method of driving a load with a characteristic such as the CCFL is a current source type. When the CCFL is in compliance (open-circuit) state, the voltage can rise to the avalanche onset level. Then, as soon as ionization occurs, the voltage will collapse and the desired operating point will be reached immediately and unambiguously. Single frequency component sinusoidal drive is preferred to maximize efficiency and minimize electromagnetic interference (EMI) [1].

The inverter that drives the CCFL is powered by 8~20 Vdc from batteries or an adaptor. The CCFL requires 1~2 kV to fire, and its inverter efficiency and size are extremely critical. The CCFL typically operates with sinusoidal voltage of 700~800 Vrms and current of 7~10 mAmp. The operation frequency is normally recommended between 25~85 kHz, and a sinusoidal lamp voltage waveform is preferable. Also, the dimming control capability is another very desirable feature for such applications. These formidable requirements demand a highly efficient conversion topology and maximum circuit integration [2-5].
The most frequently used conventional CCFL-backlight inverter circuit topology is the push-pull current-source parallel-resonant inverter (CSPRI) with a buck converter added for power regulation. In CSPRI circuits used for powering CCFL, the output voltage is sine wave, and the timing is usually based on the resonance of the transformer’s magnetizing inductance and a capacitance in parallel with the primary winding [6]. The CSPRI/buck-preregulator combination has several disadvantages such as 1) low efficiency due to two power switches in series, 2) reduced efficiency due to distorted lamp voltage and current, 3) large EMI due to hard-switching buck preregulator and unrelated switching frequencies of the preregulator and the inverter, and 4) high cost due to complex circuit topology and expensive control IC.

The current synchronous zero voltage switching (CS-ZVS) half-bridge inverter [7] is more efficient than CSPRI/buck preregulator combination, but it has also a rather complex topology, with two controlled switches, two magnetics, and three capacitors in the power train. Other drawbacks of the circuit are that 1) the leakage inductance of the transformer is not absorbed in the load network, leading to significant lamp voltage distortion and reduced efficacy, 2) the topology is claimed to be proper and can be used only with an expensive single-source dedicated control IC, and 3) when used a dedicated control IC, the inverter requires complementary metal-oxide semiconductor field effect transistors (MOSFETs), or alternatively it would require a floating driver.

The class-E single-switch inverter is based on the conventional class-E circuit topology [8,9]. The circuit has many advantages compared with the CSPRI/buck-preregulator combination and CS-ZVS half-bridge inverter circuits. The advantages are that 1) only one switch is required, 2) the leakage inductance of the transformer is absorbed in the load network, 3) the inverter is fed with an inductance, therefore the interference current reflected back to the source is small, 4) the switch voltage waveform is smooth with a low dv/dt, so the capacitive interference is reduced, and 5) the topology is public domain.

In this paper, a simple LCD CCFL-backlight resonant inverter is proposed. First, this paper has reviewed the various inverter topologies for the CCFL in this section and then, explains the proposed inverter in the following sections, in detail. Because the proposed inverter utilizes a new E-class inverter circuit and its control technique using a single-chip microcontroller, its circuit configuration is very simple. The proposed inverter is able to ensure ZVS operation under most operating conditions and performs simply the digital dimming control. It is also shown through experimental results that the proposed inverter has good performance for the LCD CCFL-backlight.

2. Proposed converter

The resonant inductor in the conventional class-E single-switch inverter is in series with the primary winding of the output transformer. This allows the absorption of the leakage inductance of the transformer in the resonant network, which leads to the reduction of the overall cost. Based on this, the resulting new class-E inverter variation of the proposed inverter is induced.

![Diagram of the proposed inverter](image-url)
C\text{r} and a transformer T that feeds the load R\text{L}, where R\text{L} denotes an equivalent resistor of the CCFL. To make the inverter as simple as possible, the transformer and inductor as one element is considered, which are that the combined magnetic device is viewed as two loosely coupled inductors wound on one core. This integrated magnetic structure can be represented by the analytic model shown in Fig. 1(b), which is widely used in power electronics. In this model, the transformer T in Fig. 1(a) comprises the ideal transformer ideal T, the magnetizing inductance L\text{m}, and the primary and secondary leakage inductance L\text{lk1} and L\text{lk2}, respectively.

The basic operation of the inverter is analyzed by considering the simplified equivalent model of Fig. 2, where the secondary leakage inductance L\text{lk2} and load R\text{L} are reflected to the primary, and the magnetizing inductance L\text{m} is replaced by a current source I\text{m}. The latter is justified under the assumption that the impedance of L\text{m} is much larger than the total reflected impedance of the secondary.

As shown in Fig. 3, the inverter has two operational modes: the boost mode and the resonance mode, and Fig. 4 shows its theoretical operation waveform.

During the boost mode in Fig. 3(a), either the switch or the diode is conducting. In this time interval, the capacitor is shorted to ground and the reflected load current n\text{load} increases exponentially. During the resonance mode in Fig. 3(b), the switch is turned off, and the inductive branch and the capacitor form a resonant network, which forces the voltage across the switch v\text{r} to follow a sinusoidal waveform. In a properly designed inverter, the sinusoidal waveform eventually returns to zero level after the anti-parallel diode catches. Then the gate drive voltage v\text{gs} can then be applied to turn on the switch under the ZVS condition. The resonant capacitor C\text{r} reduces the dv/dt across the switch at turn-off, which reduces switching losses and thereby allows its high frequency operation.

The theoretical analysis of the inverter is developed under the assumptions that 1) the switch, diode, capacitor, and inductor are ideal, 2) the magnetizing inductance L\text{m} is much larger than the leakage inductances L\text{lk1} and L\text{lk2}, and 3) the parasitic inductances and capacitors are negligible small.

The capacitor or switch voltage v\text{r} during the resonant period T\text{r} can be derived from the following set of differential equations:

\[ i_{C\text{r}} = I_{m} + n\text{load} \]
\[ v_{\text{r}} = \frac{1}{C_{\text{r}}} \int i_{\text{r}} \, dt \]
\[ V_{\text{in}} = L_{\text{lk1}} \frac{d i_{\text{C}}}{dt} + \left( \frac{L_{\text{lk2}}}{n^2} \frac{d}{dt} + R_{L} \right) n_{\text{load}} + v_{\text{r}} \]

where L\text{lk1} is the primary inductance, L\text{lk2}/n\text{2} is the reflected secondary leakage inductance, C\text{r} is the resonant capacitance, n is the turn ratio, R\text{L}=R\text{L}/n\text{2} is the reflected load resistor, R\text{L} is the lamp resistance, n\text{load} is the reflected load current or secondary current, and I\text{m} is the amplitude of the current source. The general solution of the set of differential equations (1) has the following form:

\[ v_{\text{r}} = [A_{0} \sin (\omega_{d} t) + A_{0} \cos (\omega_{d} t)] e^{-\frac{R_{L}}{2L_{m}}} + v_{n} + R_{L} I_{m} \]
where \( L_r = L_{lk1} + L_{lk2}/n^2 \), \( \omega_r = \omega_0 \sqrt{1-(1/2Q)^2} \),
\( Q = (\sqrt{L_r/C_r})/R_n \), and \( \omega_0 = 1/\sqrt{L_rC_r} \).

The integration constants \( A_1 \) and \( A_2 \) are found by the boundary conditions that \( v_r = 0 \) at \( t=0 \) and \( t=T_\lambda \). Using these conditions, the capacitor or switch voltage \( v_r \) is obtained as follows:

\[
 v_r = \left( V_{in} + R_nL_m \right) \cdot \left( \frac{\cos \theta_x - e^{\alpha t}}{\sin \theta_x} \sin(\theta_x x) - \frac{\cos \theta_x}{e^{\alpha t}} + 1 \right) \tag{3}
\]

where \( \alpha = \theta_\lambda R_n/\sqrt{1-R_n^2} \), \( \theta_x = \omega r T_\lambda \), \( x = t/T_\lambda \), and the normalized load resistance \( R_n = 1/Q \).

At steady state, the average voltage of \( v_r \) is nearly equal to \( V_{in} \) as follows:

\[
 V_{in} = \frac{1}{T_\lambda} \int_0^{T_\lambda} v_r \, dt \tag{4}
\]

Using \( v_r = 0 \) during the \( T_\lambda < t < T_\lambda \) period,

\[
 V_{in} = \frac{\alpha}{\pi R_n} \int_0^{T_\lambda} v_r \, dt \tag{5}
\]

where \( f_0 = \omega_0/2\pi \) and \( f_s \) is the switching frequency.

From (5), assuming that the inverter is lossless and equating input to output power, the normalized load current \( I_{load,n} = n I_{load,rms}/V_{in} \) is given by

\[
 I_{load,n} = R_n^{-1} \sqrt{\frac{\pi (f_s/f_0)}{4\cos \theta_\lambda - (2\cos \theta_\lambda - e^{\alpha t} - e^{-\alpha t}) + \frac{\alpha}{R_n} - 1}} \tag{6}
\]

where \( I_{load,rms} \) is the rms load current, and \( Z_e = \sqrt{L_r/C_r} \) is the characteristic impedance of the \( L_r-C_r \) resonant circuit. The theoretical results clearly point out that the inverter operates as a current source and that the output current magnitude is controlled by the switching frequency \( f_s \).

3. Implementation of the proposed inverter

![Theoretical operation waveform of the inverter](image)

[Fig. 4] The theoretical operation waveform of the inverter.

![Overall control block diagram of the inverter](image)

[Fig. 5] The overall control block diagram of the inverter.

In the microcontroller-based control system, software flexibility facilitates the development and updating of the control technique and makes the introduction of modern control theory to obtain high performance. Moreover, the single-chip microcontroller can implement the controller with lower cost and smaller size than the general-purpose microprocessor accompanying environmental circuits. Therefore, as shown in the Fig. 5, a low-cost 8-bit microcontroller PIC16C73 is utilized as the main controller of the proposed inverter. The measured voltage/current values at each point are inputted to the A/D converter and converted to digital values.
The overall inverter is divided into two parts: the controller and power circuits. The controller part includes the CPU circuit of the microcontroller PIC16C73 running the proposed control algorithms and driver circuits for driving a MOSFET. The power circuit part includes a power semiconductor switch MOSFET, a capacitor, and a transformer. The transformer turn ratio is 1:100 and its magnetizing inductance seen from the secondary winding is about 500 mH. The power semiconductor switch uses a MOSFET IRF540, whose maximum blocking voltage and drain current are 100 V and 30 A, respectively. The inverter switch is switched with high frequency, \( f_s = 55 \) kHz. DC input voltage is 12 Vdc and the rating lamp specification (about 6 W) is that the lamp voltage is 800 Vrms and the lamp current is 8 mA rms.

[Fig. 6] A simple flow-chart of the proposed inverter software program.

In order to control lamp brightness, two PWM pulses are modulated using the pseudo-logic ‘AND’ operation. Fig. 7 shows the conceptual diagram of pseudo-logic ‘AND’ by the microcontroller operation. However, when the lamp is turned off, ‘PWM OUT’ generates the minimum on-duty pulse of 55 kHz PWM for maintaining the minimum lamp current. If the minimum lamp current is maintained during the lamp turn-off period, the lamp is turned off but has the preheated effect, and thus the next initial lamp turn-on current becomes reduced. Reduction of the initial lamp turn-on current increases the CCFL’s life span [10].
[Fig. 8] The conceptual resultant waveform of ‘PWM OUT’.

The pseudo-logic ‘AND’ operation is realized by the PWM pulse generator and the timer1 interrupt. 55 kHz PWM pulse is generated through the PWM pulse generator of the microcontroller, and 100 Hz PWM is realized using the timer1 interrupt service routine. The dimming control reference signal $I_{ref}$ is generated by a 5 V variable resistor and is converted to digital value by the A/D converter of the microcontroller. After timer1 interrupt period calculation, the calculated digital reference value is loaded into timer1 count register. Fig. 8 shows the conceptual resultant waveform of the ‘PWM OUT’ by the pseudo-logic ‘AND’ operation, where $i_{load}$ is the theoretical lamp current.

4. Experimental results

In order to verify the validity of the proposed inverter, its prototype inverter has been implemented based on Section 3, and thus the following experimental results have been obtained.

(a) 25 % dimming

(b) 80 % dimming

[Fig. 9] Lamp current waveforms at each dimming state.

Fig. 9 shows the lamp current waveforms of 25 % dimming (a) and 80 % dimming (b), respectively, where the dimming means resultantly the lamp brightness. It can be seen that the initial lamp turn-on current is nearly half reduced compared with that of the conventional inverters.

[Fig. 10] Experimental waveforms of the gate drive voltage $v_g$ and the switch voltage $v_r$.

[Fig. 11] Experimental waveforms of the lamp voltage $v_{lamp}$ and the lamp current $i_{load}$. 
Fig. 10 shows experimental waveforms of the gate drive $v_{gs}$ and the switch voltage $v_r$. These waveforms show that ZVS of the proposed inverter is achieved and the inverter well generates PWM pulses and operates stably.

Fig. 11 shows waveforms of the voltage across the lamp $v_{lamp}$ and the lamp current $i_{load}$. These waveforms also show that the system operates well and stably.

In the experimental results of an actual 15-inch LCD monitor with the proposed inverter, the brightness was about 250 [cd/m$^2$], and the contrast ratio was about 250:1. These results are very similar to the CCFL BLU (Backlight Unit) performance of 15-inch class LCD monitors that are sold at a market.

5. Conclusion

In this paper, a simple LCD CCFL-backlight resonant inverter has been presented. First, this paper has reviewed the various inverter topologies for the CCFL and then has explained a modified and new E-class inverter circuit of the proposed inverter and its control technique using a single-chip microcontroller. Because the proposed inverter utilizes a simple E-class inverter circuit with a control circuit using a single-chip microcontroller, the inverter has a very simple circuit configuration. The proposed inverter can ensure ZVS operation under most operating conditions and performs simply the digital dimming control. It has also shown through experimental results that the proposed inverter has good performance for the LCD CCFL-backlight.

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